High Power LED Series
Chip on Board

LC008B Gen.2



High efficacy COB LED package, well-suited for use in spotlight applications

Features & Benefits

- Chip on Board (COB) solution makes it easy to design in
- Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability
- Completed 6,000 hours of LM-80 Testing

Applications

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination

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1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	T_a	-40 ~ +105	ºC	-
Storage Temperature	T_{stg}	-40 ~ +120	ºC	-
LED Junction Temperature	T_j	140	ºC	-
Case Temperature	Tc	105	ºC	*Note
Forward Current	I_F	430	mA	-
Power Dissipation	P_D	15.8	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	-	±0.5	kV	-

b) Electro-optical Characteristics (I_F = 240 mA, T_a = 25 ºC)

Item	Unit	Rank	Min.	Typ.	Max.
Forward Voltage (V_F)	V	YH	33.5	36.5	39.5
Color Rendering Index (R_a)	-	3	70	-	-
		5	80	-	-
		7	90	-	-
		8	95		
Thermal Resistance (junction to chip point)	ºC/W		-	2.0	-
Beam Angle	º		-	115	-
Working Voltage for Insulation	V				60
Nominal Power	W			8.6	
Eye Protection		Risk 1	-		-

Notes:

1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature (T_j = T_c = T_a = 25 °C)
2) Samsung maintains measurement tolerance of: forward voltage = ±5 %, CRI = ±1
3) Max Tc=105 ºC (1) is for ENEC condition. Refer to the derating curve, '3. Typical Characteristics Graph' for Tc limit to be designed within the range.

c) Luminous Flux Characteristics (I_F = 240 mA, T_a = 25 ºC)

CRI (R_a) Min.	Nominal CCT (K)	Flux Rank	Flux Bin	Sorting[1] @ T_c = 25 °C (lm)		Calculated Flux[2] @ T_c = 85 °C (lm)	
				Min.	Max.	Min.	Max.
70	3000	MG	M1	1064	1209	958	1088
			M2	1209	1354	1088	1219
	4000	MG	M1	1117	1270	1006	1143
			M2	1270	1422	1143	1280
	5000	MG	M1	1128	1282	1015	1154
			M2	1282	1436	1154	1292
80	2700	KG	K3	1041	1114	947	1014
			K4	1114	1187	1014	1080
		KH	K4	1114	1187	1014	1080
			K5	1187	1260	1080	1147
	3000	KG	K3	1108	1185	1008	1078
			K4	1185	1263	1078	1149
		KH	K4	1185	1263	1078	1149
			K5	1263	1340	1149	1219
	3500	KG	K3	1141	1221	1038	1111
			K4	1221	1300	1111	1183
		KH	K4	1221	1300	1111	1183
			K5	1300	1380	1183	1256
	4000	KG	K3	1174	1256	1068	1143
			K4	1256	1338	1143	1218
		KH	K4	1256	1338	1143	1218
	5000	KG	K3	1185	1268	1078	1154
			K4	1268	1351	1154	1229
		KH	K4	1268	1351	1154	1229
	5700	KG	K3	1185	1268	1078	1154
			K4	1268	1351	1154	1229
		KH	K4	1268	1351	1154	1229

c) Luminous Flux Characteristics (I_F = 240 mA, T_a = 25 ºC)

CRI (R_a) Min.	Nominal CCT (K)	Flux Rank	Flux Bin	Sorting[1] @ T_c = 25 °C (lm)		Calculated Flux[2] @ T_c = 85 °C (lm)	
				Min.	Max.	Min.	Max.
90	2700	FH	F3	933	1008	849	917
			F4	1008	1083	917	985
	3000	FH	F3	952	1029	867	936
			F4	1029	1105	936	1005
	3500	FH	F3	981	1060	893	964
			F4	1060	1138	964	1036
	4000	FH	F3	1010	1090	919	992
			F4	1090	1171	992	1066
95	2700	EC	E1	756	840	688	764
			E2	840	924	764	841
	3000	EC	E1	779	866	709	788
			E2	866	953	788	867
	3500	EC	E1	803	892	731	812
			E2	892	981	812	893

Notes:

1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature (T_j = T_c = T_a = 25 °C)
2) Calculated flux values are for reference only
3) Samsung maintains measurement tolerance of: luminous flux = ±7 %, CRI = ±1

2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	P	H	C	W	1	H	D	N	9	4	5	Y	H	R	T	K	E

Digit	PKG Information	Code	Specification
1 2 3	Samsung Package High Power	SPH	
4 5	Color	WW	Warm White (T/U/V/W Ranks)
		CW	Cool White (Q/R Ranks)
6	Product Version	1	
7 8	Form Factor	HD	COB
9	Lens Type	N	No lens
10	Internal Code	9	LC008
11	Chip Type	4	
12	CRI & Sorting Temperature	3	Min. 70
		5	Min. 80 25 °C
		7	Min. 90
		8	Min 95
13 14	Forward Voltage (V)	YH	33.5~39.5
15	CCT (K)	W	2700 K Bin Code: WA,WB (MacAdam Ellipse)
		V	3000 K Bin Code: VA, VB (MacAdam Ellipse) VW, VX, VY, VZ (ANSI bin)
		U	3500 K Bin Code: UA, UB (MacAdam Ellipse)
		T	4000 K Bin Code: TA, TB (MacAdam Ellipse) TW, TX, TY, TZ (ANSI bin)
		R	5000 K Bin Code: RA (MacAdam Ellipse) RW, RX, RY, RZ (ANSI bin)
		Q	5700 K QW, QX, QY, QZ (ANSI bin)
16	MacAdam / ANSI	2	MacAdam 2-step
		3	MacAdam 3-step
		T	ANSI bin
17 18	Luminous Flux	MG	Bin Code: M1, M2 (70 CRI)
		KG	K3, K4 (80 CRI)
		KH	K4, K5 (80 CRI)
		FH	F3, F4 (90 CRI)
		EC	E1, E2 (95 CRI)

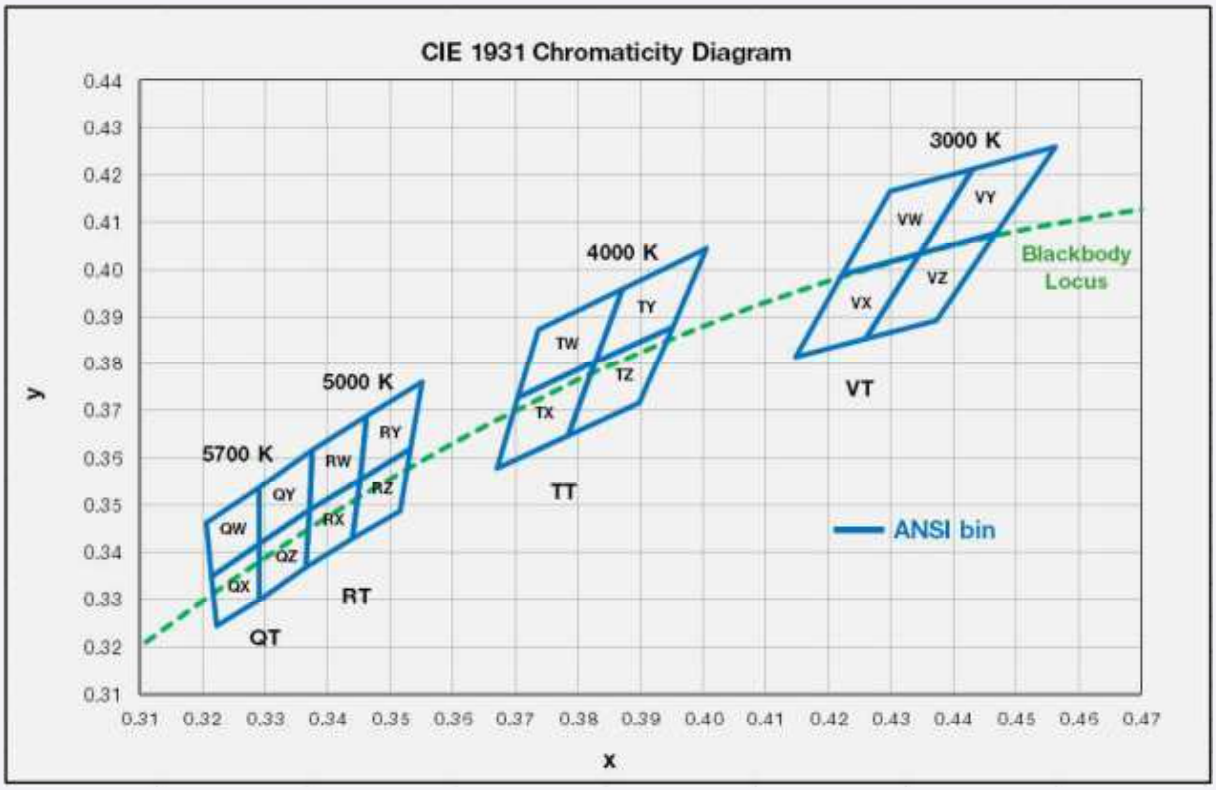
a) Binning Structure (I_F = 240 mA, T_a = 25 ºC)

CRI (R_a) Min.	Nominal CCT (K)	Product Code	V_F Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ_v, lm)
70	3000	SPHWW1HDN943YHVTMG	YH	VT	VW, VX VY, VZ	MG	M1	1064 ~ 1209
							M2	1209 ~ 1354
	4000	SPHWW1HDN943YHTTMG	YH	TT	TW, TX TY, TZ	MG	M1	1117 ~ 1270
							M2	1270 ~ 1422
	5000	SPHCW1HDN943YHRTMG	YH	RT	RW, RX RY, RZ	MG	M1	1128 ~ 1282
							M2	1282 ~ 1436
80	2700	SPHWW1HDN945YHW2KG	YH	W2	WB	KG	K3	1041 ~ 1114
							K4	1114 ~ 1187
		SPHWW1HDN945YHW3KG	YH	W3	WA, WB	KG	K3	1041 ~ 1114
							K4	1114 ~ 1187
		SPHWW1HDN945YHW2KH	YH	W2	WB	KH	K4	1114 ~ 1187
							K5	1187 ~ 1260
		SPHWW1HDN945YHW3KH	YH	W3	WA, WB	KH	K4	1114 ~ 1187
							K5	1187 ~ 1260
	3000	SPHWW1HDN945YHV2KG	YH	V2	VB	KG	K3	1108 ~ 1185
							K4	1185 ~ 1263
		SPHWW1HDN945YHV3KG	YH	V3	VA, VB	KG	K3	1108 ~ 1185
							K4	1185 ~ 1263
		SPHWW1HDN945YHV2KH	YH	V2	VB	KH	K4	1185 ~ 1263
							K5	1263 ~ 1340
		SPHWW1HDN945YHV3KH	YH	V3	VA, VB	KH	K4	1185 ~ 1263
							K5	1263 ~ 1340
	3500	SPHWW1HDN945YHU2KG	YH	U2	UB	KG	K3	1141 ~ 1221
							K4	1221 ~ 1300
		SPHWW1HDN945YHU3KG	YH	U3	UA, UB	KG	K3	1141 ~ 1221
							K4	1221 ~ 1300
		SPHWW1HDN945YHU2KH	YH	U2	UB	KH	K4	1221 ~ 1300
							K5	1300 ~ 1380
		SPHWW1HDN945YHU3KH	YH	U3	UA, UB	KH	K4	1221 ~ 1300
							K5	1300 ~ 1380
	4000	SPHWW1HDN945YHT2KG	YH	T2	TB	KG	K3	1174 ~ 1256
							K4	1256 ~ 1338
		SPHWW1HDN945YHT3KG	YH	T3	TA, TB	KG	K3	1174 ~ 1256
							K4	1256 ~ 1338
		SPHWW1HDN945YHT2KH	YH	T2	TB	KH	K4	1256 ~ 1338
		SPHWW1HDN945YHT3KH	YH	T3	TA, TB	KH	K4	1256 ~ 1338
	5000	SPHCW1HDN945YHR3KG	YH	R3	RA	KG	K3	1185 ~ 1268
							K4	1268 ~ 1351
		SPHCW1HDN945YHRTKG	YH	RT	RW, RX, RY, RZ	KG	K3	1185 ~ 1268
							K4	1268 ~ 1351
		SPHCW1HDN945YHR3KH	YH	R3	RA	KH	K4	1268 ~ 1351
		SPHCW1HDN945YHRTKH	YH	RT	RW, RX, RY, RZ	KH	K4	1268 ~ 1351
	5700	SPHCW1HDN945YHQTKG	YH	QT	QW, QX, QY, QZ	KG	K3	1185 ~ 1268
							K4	1268 ~ 1351
		SPHCW1HDN945YHQTKH	YH	QT	QW, QX, QY, QZ	KH	K4	1268 ~ 1351

a) Binning Structure (I_F = 240 mA, T_a = 25 ºC)

CRI (R_a) Min.	Nominal CCT (K)	Product Code	V_F Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ_v, lm)
90	2700	SPHWW1HDN947YHW2FG	YH	W2	WB	FG	F3	933 ~ 1008
							F4	1008 ~ 1083
		SPHWW1HDN947YHW3FG	YH	W3	WA, WB	FG	F3	933 ~ 1008
							F4	1008 ~ 1083
	3000	SPHWW1HDN947YHV2FG	YH	V2	VB	FG	F3	952 ~ 1029
							F4	1029 ~ 1105
		SPHWW1HDN947YHV3FG	YH	V3	VA, VB	FG	F3	952 ~ 1029
							F4	1029 ~ 1105
	3500	SPHWW1HDN947YHU2FG	YH	U2	UB	FG	F3	981 ~ 1060
							F4	1060 ~ 1138
		SPHWW1HDN947YHU3FG	YH	U3	UA, UB	FG	F3	981 ~ 1060
							F4	1060 ~ 1138
	4000	SPHWW1HDN947YHT2FG	YH	T2	TB	FG	F3	1010 ~ 1090
							F4	1090 ~ 1171
		SPHWW1HDN947YHT3FG	YH	T3	TA, TB	FG	F3	1010 ~ 1090
							F4	1090 ~ 1171
95	2700	SPHWW1HDN948YHW2EC	YH	W2	WB	EC	E1	756 ~ 840
							E2	840 ~ 924
		SPHWW1HDN948YHW3EC	YH	W3	WA,WB	EC	E1	756 ~ 840
							E2	840 ~ 924
	3000	SPHWW1HDN948YHV2EC	YH	V2	VB	EC	E1	779 ~ 866
							E2	866 ~ 953
		SPHWW1HDN948YHV3EC	YH	V3	VA,VB	EC	E1	779 ~ 866
							E2	866 ~ 953
	3500	SPHWW1HDN948YHU2EC	YH	U2	UB	EC	E1	803 ~ 892
							E2	892 ~ 981
		SPHWW1HDN948YHU3EC	YH	U3	UA,UB	EC	E1	803 ~ 892
							E2	892 ~ 981

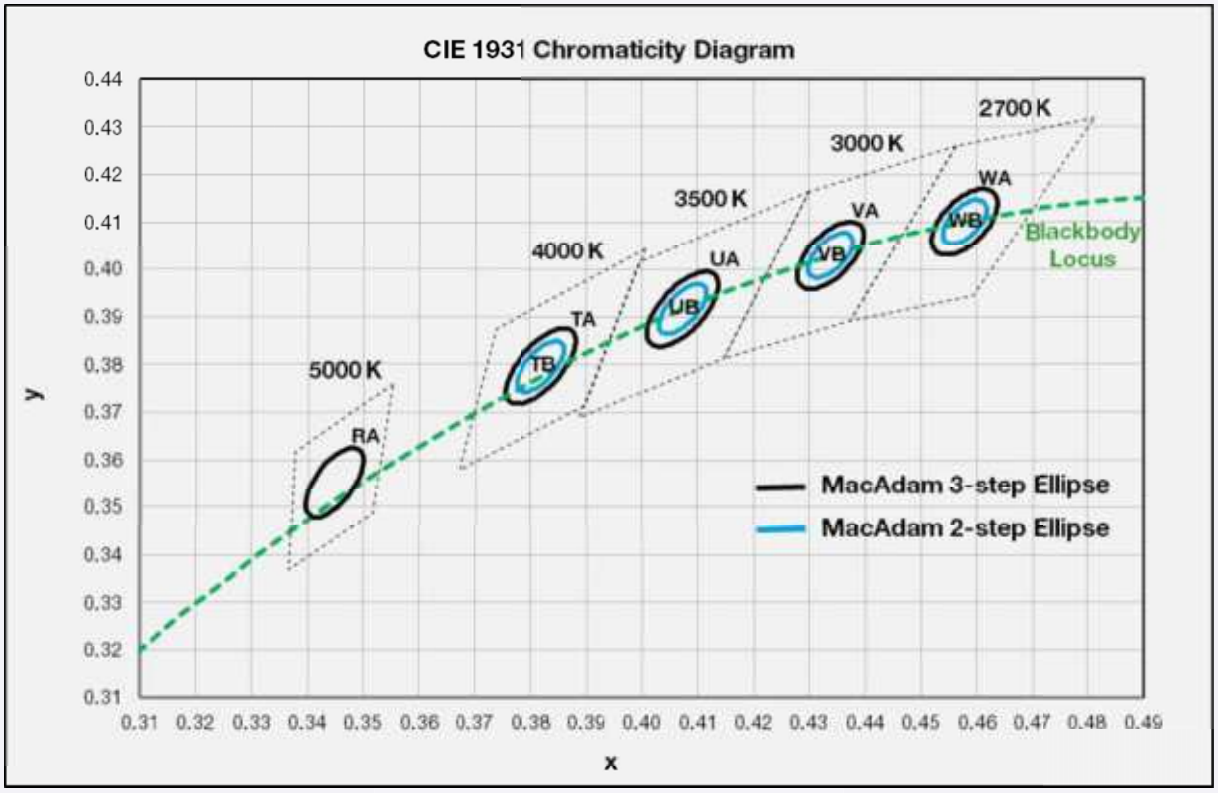
b) Chromaticity Region & Coordinates (I_F = 240 mA, T_a = 25 ºC)

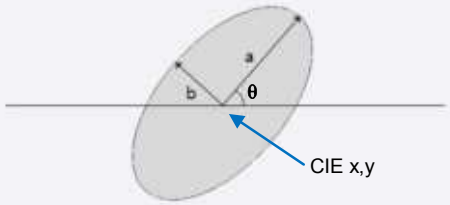


Region	CIE x	CIE y	Region	CIE x	CIE y
V rank (3000 K)					
VW	0.4223	0.399	VY	0.4345	0.4033
	0.4345	0.4033		0.4468	0.4077
	0.4431	0.4213		0.4562	0.4260
	0.4299	0.4165		0.4431	0.4213
VX	0.4223	0.399	VZ	0.4260	0.3854
	0.4147	0.3814		0.4373	0.3893
	0.4260	0.3854		0.4468	0.4077
	0.4345	0.4033		0.4345	0.4033
R rank (5000 K)					
RW	0.3376	0.3616	RY	0.3463	0.3687
	0.3463	0.3687		0.3551	0.3760
	0.3451	0.3554		0.3533	0.3620
	0.3371	0.3490		0.3451	0.3554
RX	0.3371	0.3490	RZ	0.3451	0.3554
	0.3451	0.3554		0.3533	0.3620
	0.3440	0.3428		0.3515	0.3487
	0.3366	0.3369		0.3440	0.3428

Region	CIE x	CIE y	Region	CIE x	CIE y
T rank (4000 K)					
TW	0.3736	0.3874	TY	0.3871	0.3959
	0.3871	0.3959		0.4006	0.4044
	0.3828	0.3803		0.3952	0.388
	0.3703	0.3726		0.3828	0.3803
TX	0.3703	0.3726	TZ	0.3828	0.3803
	0.3828	0.3803		0.3952	0.388
	0.3784	0.3647		0.3898	0.3716
	0.367	0.3578		0.3784	0.3647
Q rank (5700 K)					
QW	0.3207	0.3462	QY	0.3290	0.3538
	0.3290	0.3538		0.3376	0.3616
	0.3290	0.3417		0.3371	0.3490
	0.3215	0.3350		0.3290	0.3417
QX	0.3215	0.3350	QZ	0.3290	0.3417
	0.3290	0.3417		0.3371	0.3490
	0.3290	0.3300		0.3366	0.3369
	0.3222	0.3243		0.3290	0.3300

b) Chromaticity Region & Coordinates (I_F = 240 mA, T_a = 25 ºC)





MacAdam Ellipse (WA, WB)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4578	0.4101	53.70	0.0054	0.0028
3-step	0.4578	0.4101	53.70	0.0081	0.0042

MacAdam Ellipse (VA, VB)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4338	0.403	53.22	0.0056	0.0027
3-step	0.4338	0.4030	53.22	0.0083	0.0041

MacAdam Ellipse (UA, UB)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4073	0.3917	54.00	0.0062	0.0028
3-step	0.4073	0.3917	54.00	0.0093	0.0041

MacAdam Ellipse (TA, TB)					
Step	CIE x	CIE y	θ	a	b
2-step	0.3818	0.3797	53.72	0.0063	0.0027
3-step	0.3818	0.3797	53.72	0.0094	0.0040

MacAdam Ellipse (RA)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3447	0.3553	59.62	0.0082	0.0035

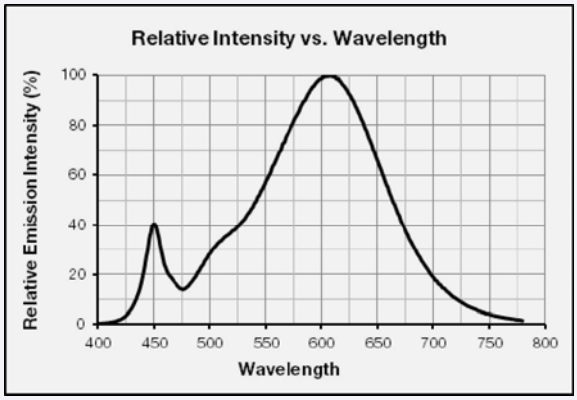
Note:

Samsung maintains measurement tolerance of: Cx, Cy = ±0.005

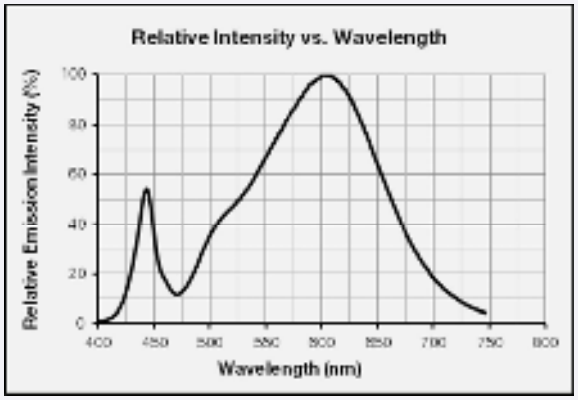
3. Typical Characteristics Graphs

a) Spectrum Distribution (I_F = 240 mA, T_a = 25 ºC)

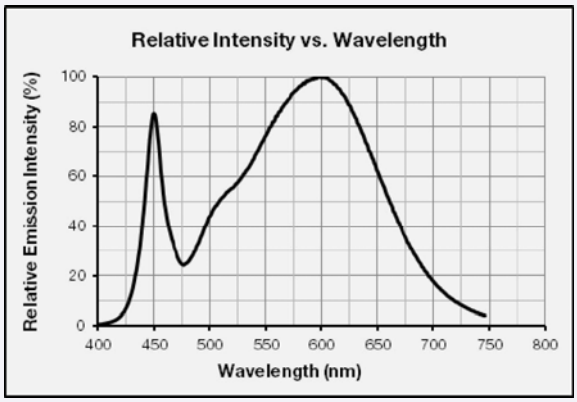
CCT: 2700 K



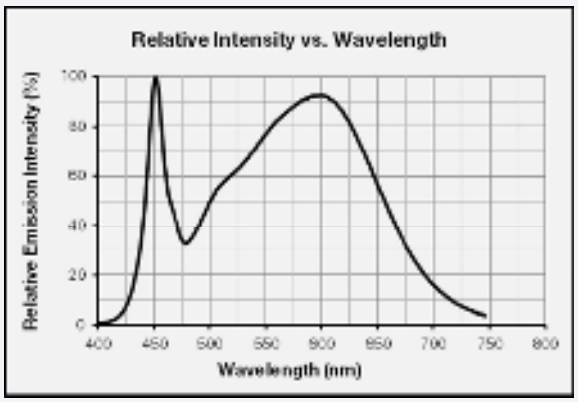
CCT: 3000 K



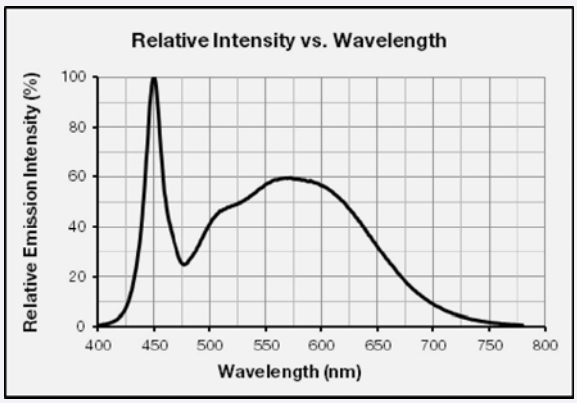
CCT: 3500 K



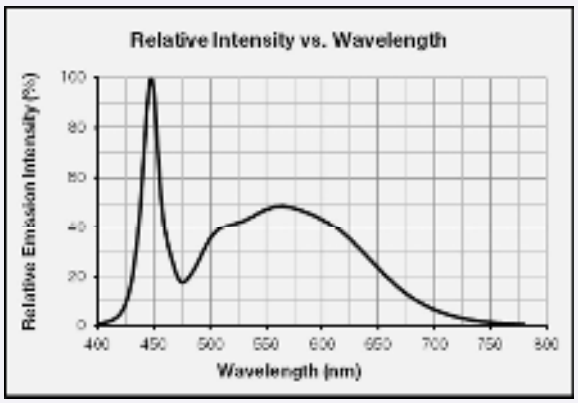
CCT: 4000 K



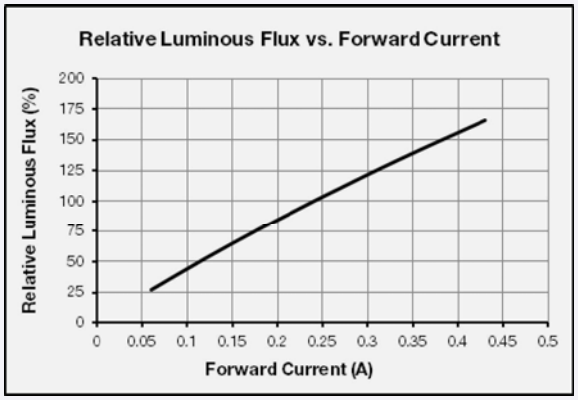
CCT: 5000 K

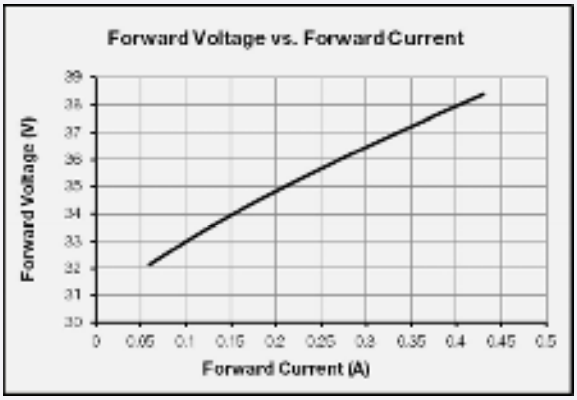


CCT: 5700 K

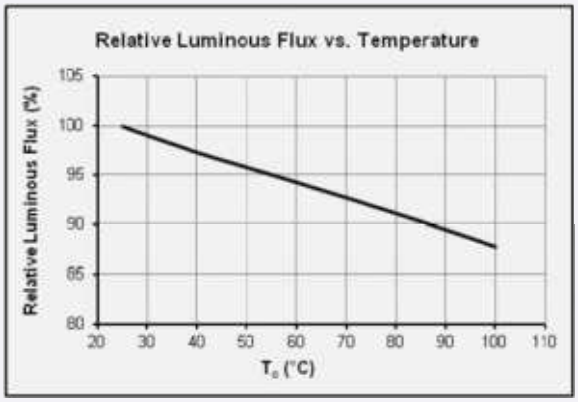


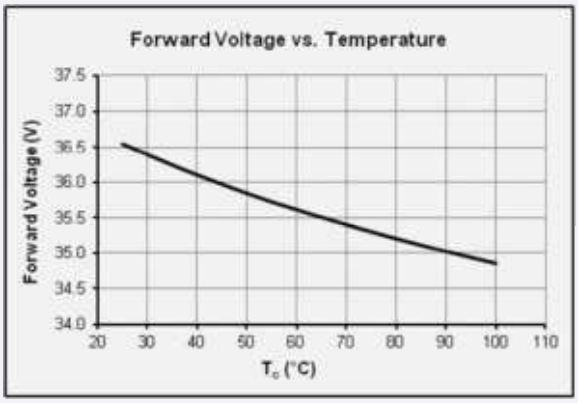
b) Forward Current Characteristics (T_a = 25 ºC)



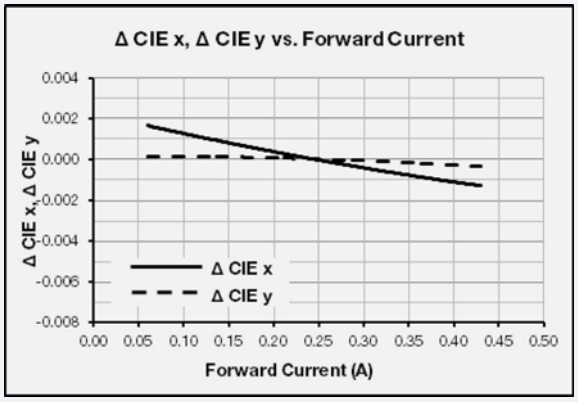


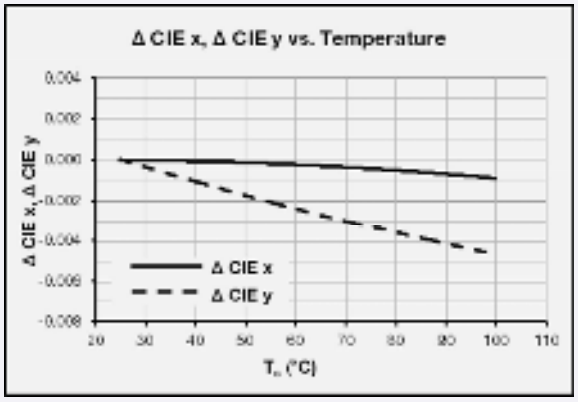
c) Temperature Characteristics (I_F = 240 mA)



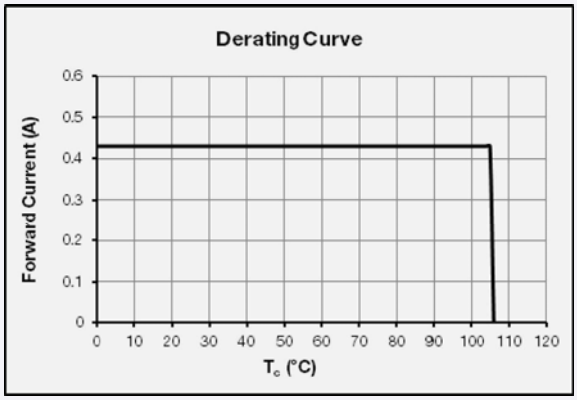


d) Color Shift Characteristics T_a = 25 ºC I_F = 240 mA

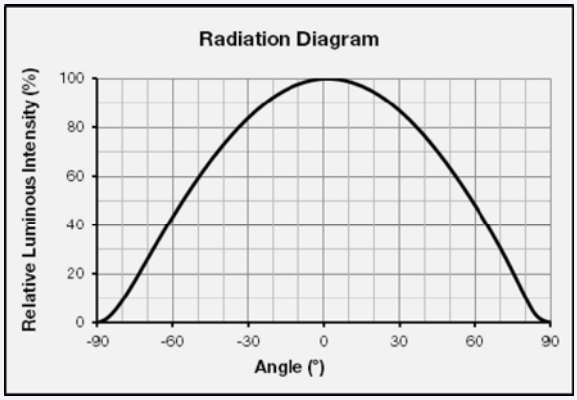




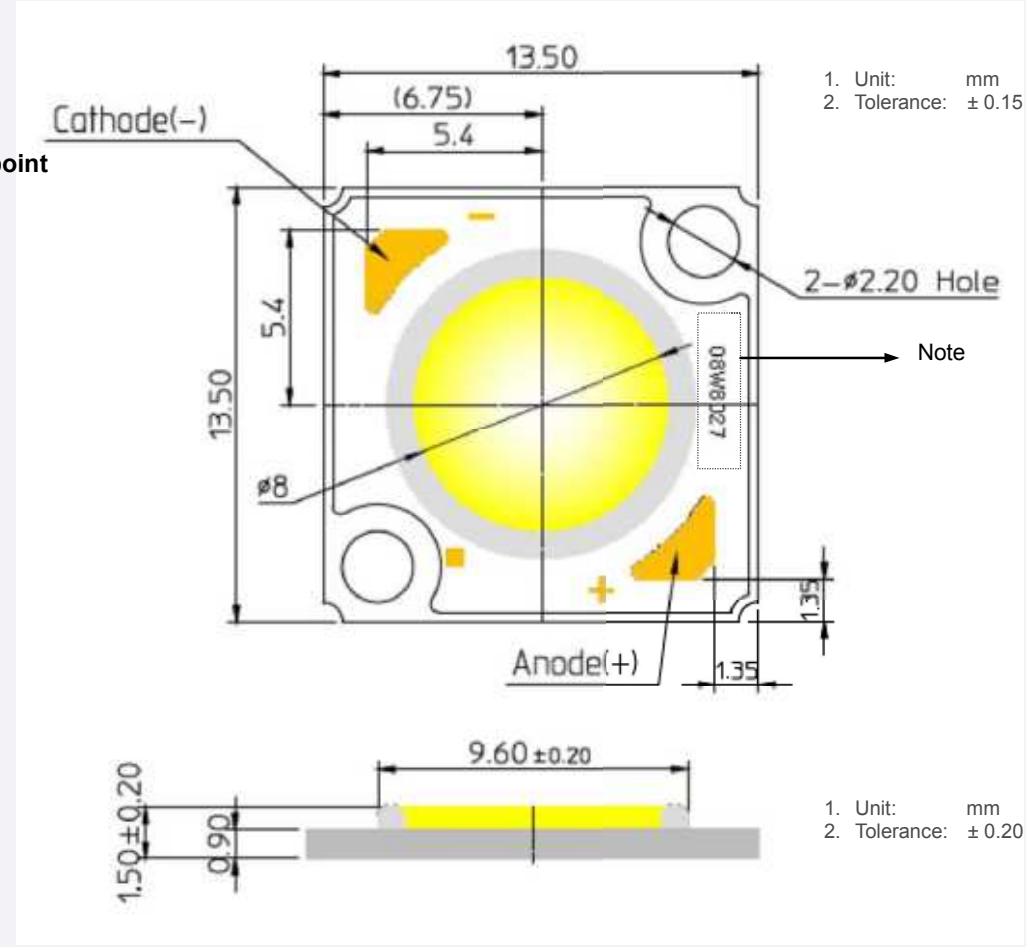
e) Derating Curve



f) Beam Angle Characteristics (I_F = 240 mA, T_a = 25 °C)



4. Outline Drawing & Dimension



1. Unit: mm
2. Tolerance: ± 0.15 mm

1. Unit: mm
2. Tolerance: ± 0.20 mm

Item	Dimension	Tolerance	Unit
Length	13.50	±0.15	mm
Width	13.50	±0.15	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	8	±0.15	mm
Screw Hole Size	2.2	±0.15	mm

Note: Denoted product information above is only an example
(08W8027 : 8.6W, CRI80+, 2700K)

5. Reliability Test Items & Conditions

a) Test Items

Test Item	Test Condition	Test Hour / Cycle
Room Temperature Life Test	25 °C, I_F = max	1000 h
High Temperature Humidity Life Test	60 °C, 90 % RH, DC Derating, I_F = max	1000 h
High Temperature Life Test	105 °C, DC Derating, I_F = max	1000 h
Low Temperature Life Test	-40 °C, DC 430 mA	1000 h
High Temperature Storage	120 °C	1000 h
Low Temperature Storage	-40 °C	1000 h
Thermal Shock	-45 °C / 15 min ↔ 125 °C / 15 min temperature change in 5 min	200 cycles
Temperature Cycle On/Off Test	-40 °C / 85 °C each 20 min, 100 min transfer power on/off each 5 min, DC 240 mA	100 cycles
ESD (HBM)	R_1: 10 MΩ R_2: 1.5 kΩ C: 100 pF V: ±2 kV	5 times
ESD (MM)	R_1: 10 MΩ R_2: 0 kΩ C: 200 pF V: ±0.5 kV	5 times
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔ max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500 g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Salt Spray Test	35 °C, 5 % salt water 8 h spray, 16 h dwell	2 cycles

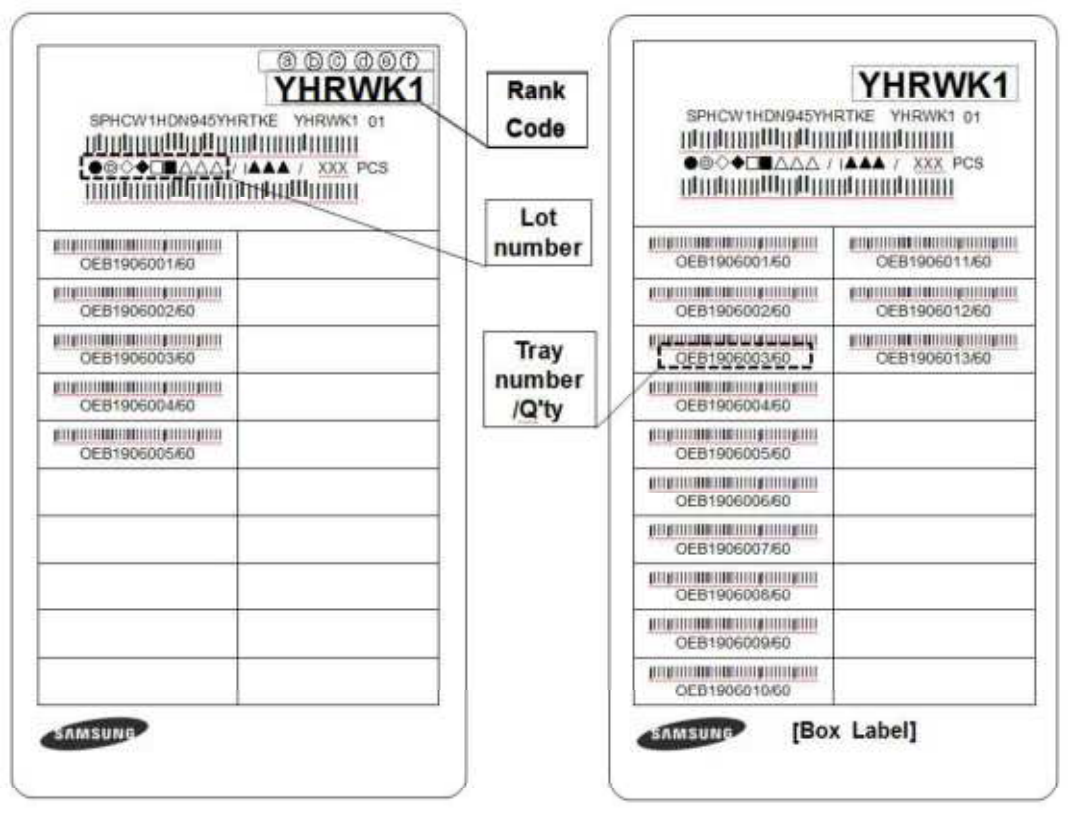
b) Criteria for Judging the Damage

Item	Symbol	Test Condition (T_c = 25 °C)	Limit	
			Min.	Max.
Forward Voltage	V_F	I_F = 240 mA	L.S.L. * 0.9	U.S.L. * 1.1
Luminous Flux	Φ_v	I_F = 240 mA	L.S.L * 0.7	U.S.L * 1.3

6. Label Structure

a) Label Structure

Aluminum Bag & Inner Box **Outer Box**



Note: Denoted rank code and product code above is only an example (see description on page 5)

Rank Code:

ⓐⓑ: Forward Voltage rank (refer to page 6-7)

ⓒⓓ: Chromaticity bin (refer to page 8-9)

ⓔⓕ: Luminous Flux bin (refer to page 6-7)

b) Lot Number

The lot number is composed of the following characters:

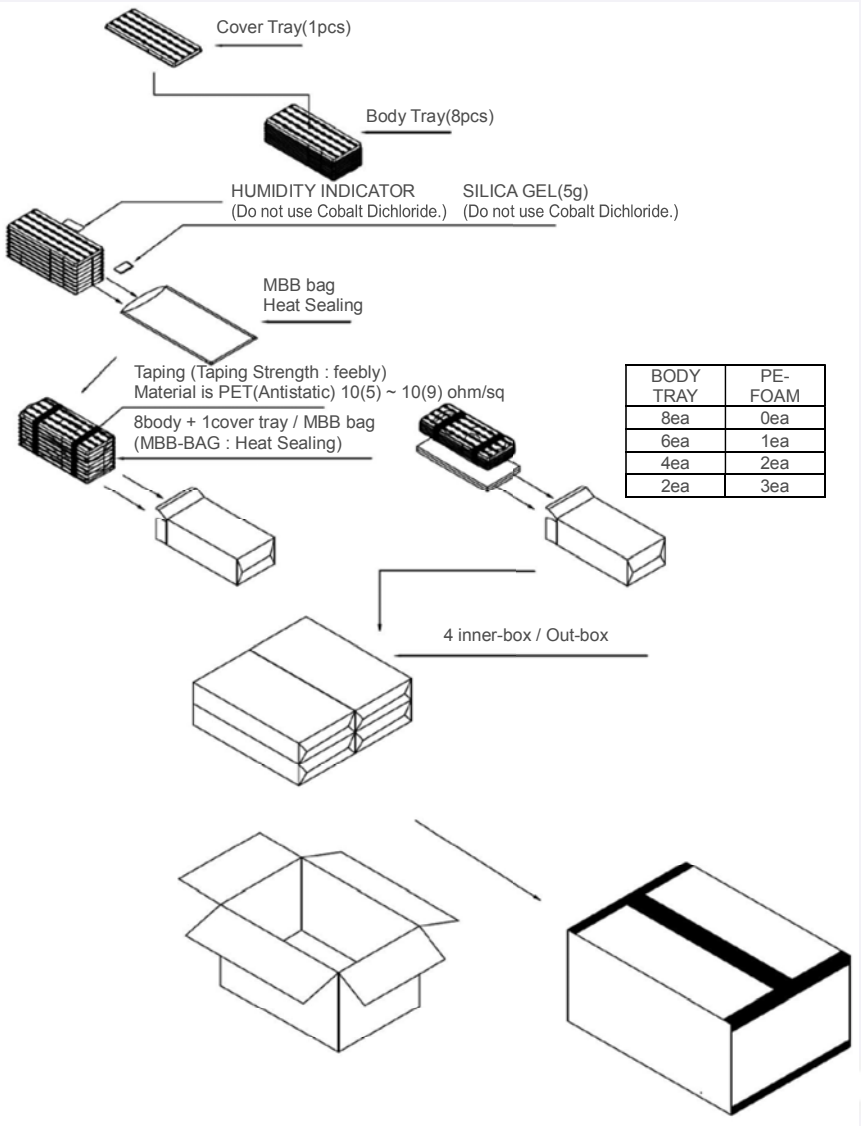
●◎◇◆□■△△△ / 1▲▲▲ / xxx PCS

●	:	Production site (S: Giheung, Korea, G: Tianjin, China)
◎	:	L (LED)
◇	:	Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
◆	:	Year (Y: 2014, Z: 2015, A: 2016, …)
□	:	Month (1~9, A, B, C)
■	:	Day (1~9, A, B~V)
△△△	:	Product serial number (001 ~ 009)
▲▲▲	:	Tray number (001 ~ 999)

7. Packing Structure

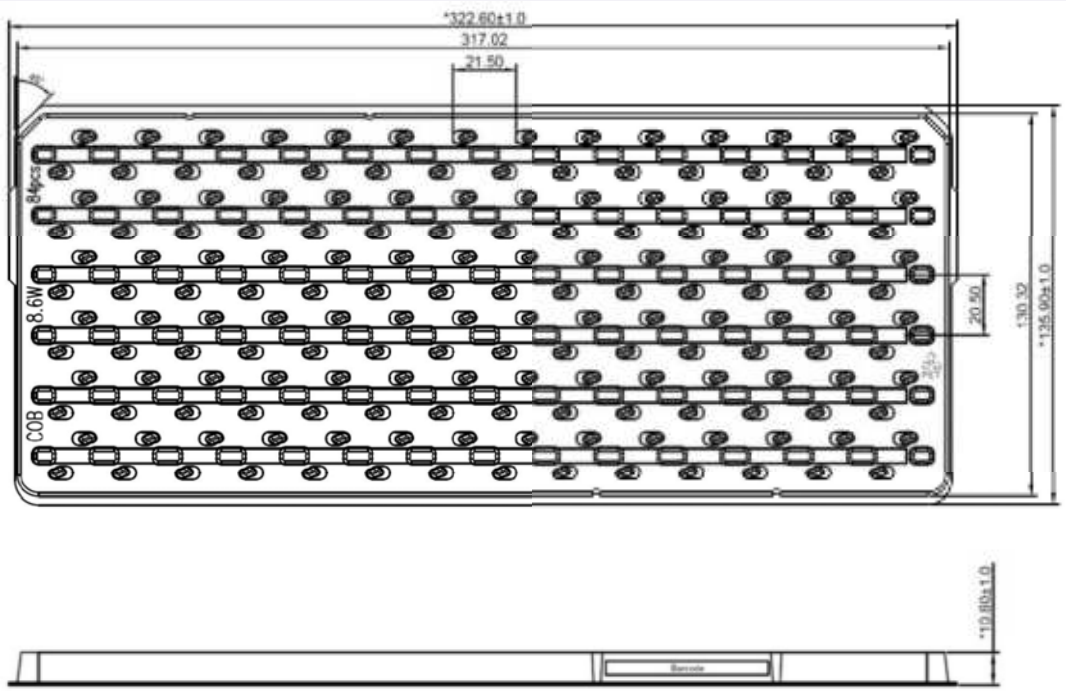
Packing material	Max. quantity in pcs of COB	Dimension (mm)			
		Length	Width	Height	Tolerance
Tray	84	322.6	135.9	10.8	1.0
Aluminum Bag	672 (8 trays)	450	230	-	10
PE Foam Pad	-	280	130	10	2
Inner Box	672 (1 aluminum bag)	338	143	55	2
Outer Box	2,688 (4 inner boxes)	351	303	125	5
Pallet	150,528 (56 outer boxes)	1000	1000	130	10

a) Packing Structure

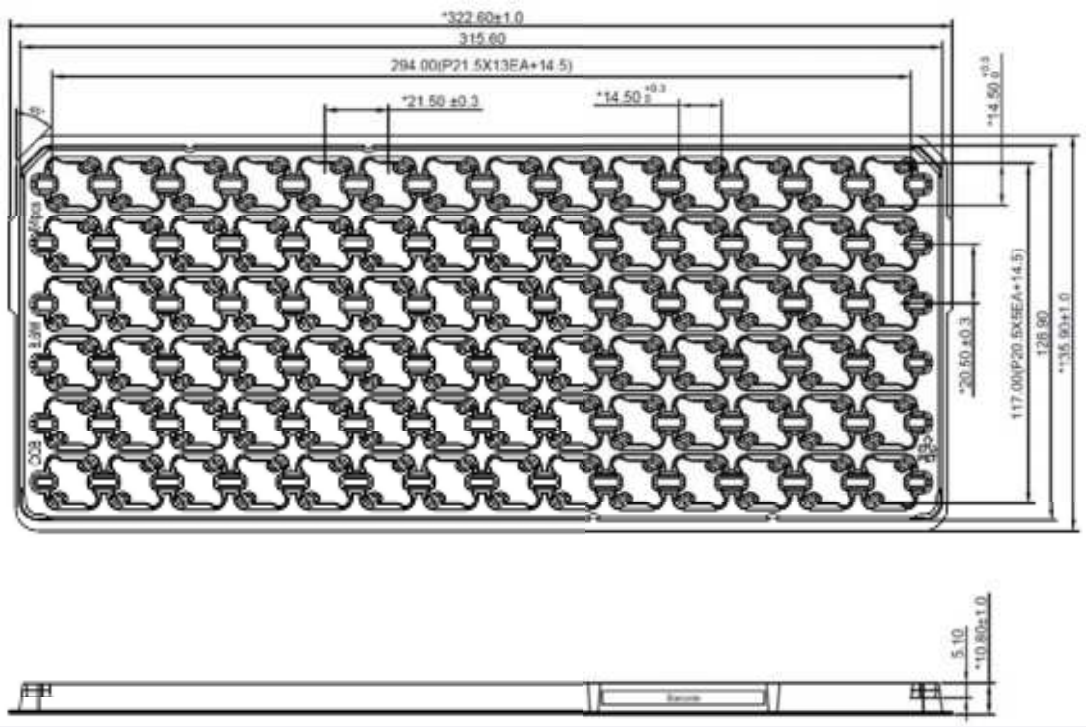


b) Tray

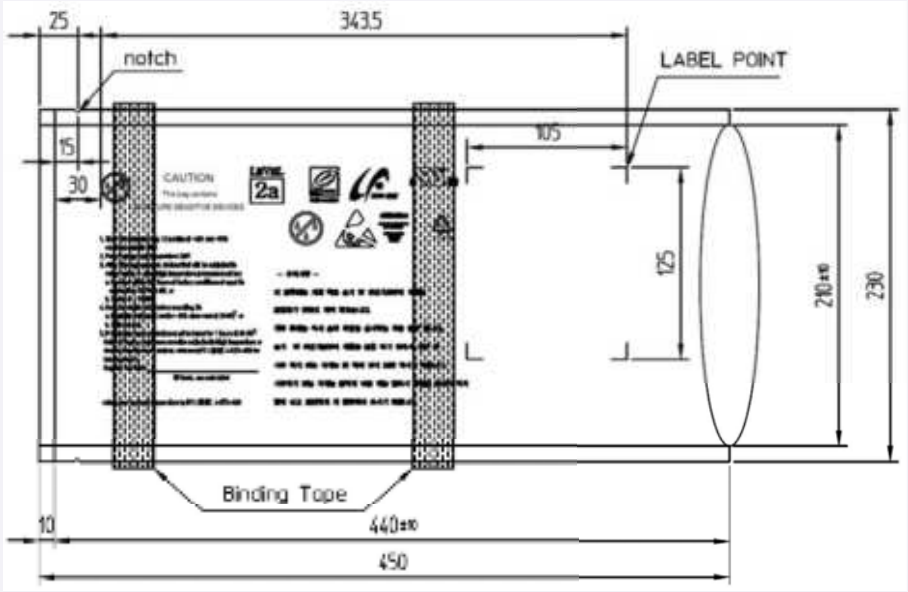
① COVER



② BODY

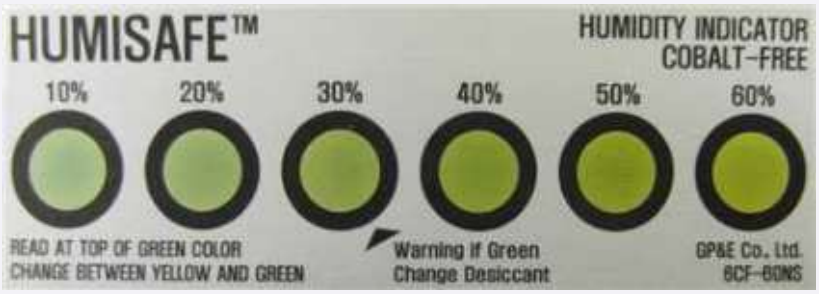


c) Aluminum Vinyl Packing Bag



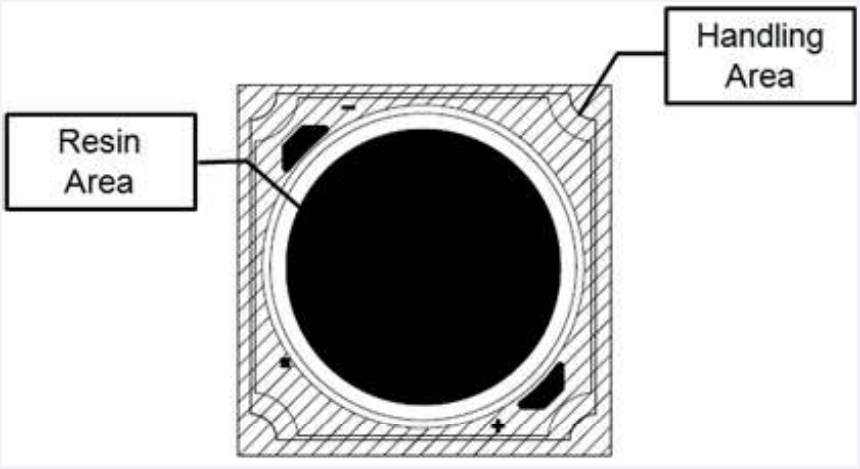
d) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Packing Bag





8. Precautions in Handling & Use

1) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 ºC, 0~90 % RH).
3) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
   a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 ºC / 60 % RH, or
   b. Stored at <10 % RH
4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
5) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 ºC.
6) Devices must be baked for 1 hour at 60 ± 5 ºC, if baking is required.
7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
8) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
9) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.



Legal and additional information.

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